

# SIHH11N65E-T1-GE3

## SIHH11N65E-T1-GE3 Information

they helsener a th	 SIHH11N65E-T1-GE3 Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CHAN 650V 12A POWERPAK 8-PowerTDFN For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# SIHH11N65E-T1-GE3 Specifications

Manufacturer Part Number	SIHH11N65E-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	12A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	68nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1257pF @ 100V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	130W (Tc)
Rds On (Max) @ Id, Vgs	363 mOhm @ 6A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PowerPAK? 8 x 8
Package / Case	8-PowerTDFN
	Report errors?

### SIHH11N65E-T1-GE3 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SIHH11N65E-T1-GE3 Payment Methods



If you have any question about SIHH11N65E-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com